

FAN7585 Intelligent Voltage Mode PWM IC

Features

- · Complete PWM Control and House Keeping Circuitry
- Few External Components
- Precision Voltage Reference Trimmed to 2%
- Dual Output for Push-Pull Operation
- · Each Output TR for 200mA Sink Current
- Variable Duty Cycle by Dead Time Control
- Soft Start Capability by Using Dead Time Control
- Double Pulse Suppression Logic
- Over Voltage Protection for 3.3V/5V/12V
- Under Voltage Protection for 3.3V/5V/12V
- Over Current Protection for 3.3V/5V/12V
- One More External Input for Various Protection (PT)
- Remote On/Off Control Function (PS-ON)
- Latch Function Controlled by Remote and Protection Input
- · Power Good Signal Generator with Hysteresis

Typical Application

• PC Power Supply



Description

The FAN7585 is a fixed frequency improved performance pulse width modulation control circuit with complete housekeeping circuitry for use in the secondary side of SMPS (Switched Mode Power Supply). It contains various functions, which are overvoltage protection, undervoltage protection, over current protection, remote on/off control, power good signal generator, etc.

OVP (Over Voltage Protection) Section

It has OVP functions for +3.3V,+5V,+12V outputs and PT. The circuit is made up of a comparator with four detecting inputs and without hysteresis voltage. Especially, PT (Pin19) is prepared for an extra OVP input or another protection signal.

UVP (Under Voltage Protection) Section

It also has UVP functions for +3.3V, +5V, +12V outputs. The block is made up of a comparator with three detecting inputs and without hysteresis voltage.

OCP (Over Current Protection) Section

It has precision OCP functions for +3.3V, +5V, +12V outputs. The block is made up of three comparators with current source setting function. Two inputs of each OCP comparator are connected to both sides of current sensing inductor that is located in the secondary output of SMPS.

Remote On/Off Section

The remote on/off section is used to control SMPS externally. If a high signal or open state is supplied to the remote on/off input, PWM signal becomes a high state and all secondary outputs are grounded. The remote on/off signal is transferred with some on-delay and off-delay time of 8ms, 24ms respectively.

Precision Reference Section

The reference voltage is trimmed to $\pm 2\%$. (4.9V \leq Vref \leq 5.1V)

PG (Power Good Signal Generator) Section

The power good signal generator is to monitor the voltage level of power supply for safe operation of a microprocessor having some delay time at turn-on. The power good output should be low state before the output voltatge is out of regulation at turn-off.

Internal Block Diagram



Pin Definition



Pin Description

Pin Number	Pin Name	I/O	Pin Function Description	Pin Number	Pin Name	I/O	Pin Function Description
1	Vcc	Ι	Supply Voltage	13	IS33	Ι	OCP Input for +3.3V
2	COMP	0	E/A Output	14	V33	Ι	OVP, UVP Input for +3.3V
3	E/A(-)	Ι	E/A (-) Input	15	IS5	Ι	OCP Input for +5V
4	E/A(+)	I	E/A (+) Input	16	V5	I	OVP, UVP Input for 5V
5	TREM	-	Remote On/Off Delay	17	IS12	I	OCP Input for +12V
6	REM	I	Remote On/Off Input	18	V12	I	OVP, UVP Input for +12V
7	RT/CT	-	Oscillation Freq. Setting R,C	19	PT	I	Extra Protection Input
8	RI	-	OCP Current Setting R	20	TUVP	-	UVP Delay
9	DET	I	Detect Input	21	DTC	I	Deadtime Control Input
10	TPG	-	PG Delay	22	C2	0	Output 2
11	PG	0	Power Good Signal Output	23	GND	-	Ground
12	Vref	0	Precision Reference Voltage	24	C1	0	Output 1

Pin Function

Pin Number	Pin Name	Pin Function Description
1	Vcc	Supply voltage. Operating range is 15V~30V. Test condition : V _{CC} =20V, Ta=25°C.
2	COMP	Error amplifier output. It is connected to non-inverting input of pulse width modulator comparator.
3	E/A(-)	Error amplifier inverting input. Its reference voltage is always 1.25V.
4	E/A(+)	Error amplifier non-inverting input feedback voltage. This pin may be used to sense power supply output voltages.
5	TREM	Remote On/Off delay. Ton/Toff=8ms/24ms (Typ.) with C=0.1uF. Its High/Low threshold voltages are 1.8V/0.6V.
6	REM	Remote On/Off input. It is TTL operation and its threshold voltage is 1.4V. Voltage at this pin can reach normal 4.6V, with absolute maximum voltage, 5.25V. If REM = "Low", PWM = "Low", that means the main SMPS is operational. when REM = "High", then PWM = "High" and the main SMPS is turned-off.
7	R _T /C _T	Oscillation frequency setting R, C.(Test condition $RT = 10k\Omega$)
8	RI	OCP current setting pin. You can fix the OCP reference current (Iref1) by using RI resistor.
9	DET	AC input under voltage detection pin. Its threshold voltage is 1.25V Typ.
10	TPG	PG delay. Td =260ms (Typ.) with CTPG = 2.2uF. The High/Low threshold voltages are 1.8V/0.6V and the voltage of Pin10 is clamped to 2.9V for noise margin.
11	PG	Power Good output signal. PG = "High" means that the power is "Good" for operation and PG = "Low" means "Power fail".
12	Vref	Precision voltage reference is trimmed to $\pm 2\%$ (Typical Value = 5V).
13	IS33	Current sense input for +3.3V output. This pin is connected to the current sensing resistor or inductor. You can define OCP offset voltage for +3.3V by using RI resistor externally. If you connect $62k\Omega$ at pin 8 to ground, the reference current(Iref1) should be 20uA. After that , you can make a constant OCP offset voltage(Voffset=Roffset*5*20uA). In case the voltage drop(IO.33*Rs) of the sense resistor or inductor is larger than offset voltage, after OCP delay time the main SMPS is turned off. So the over current level is determined by the following equation. IO.33=Voffset/Rs.
14	V33	OVP, UVP input for +3.3V output (Typical Value = 4.1V/2.3V).
15	IS5	Current sense input for +5V output. You can make +5V OCP function as the previous method in IS5(pin15).
16	V5	OVP, UVP input for +5V output (Typical Value = 6.4V/4.0V).
17	IS12	Current sense input for +12V output. You can make +12V OCP function as the previous method in IS12(pin17).
18	V12	OVP, UVP input for 12V output (Typical Value = 14.2V/10V).
19	PT	This is prepared for an extra OVP input or another protection signal (Typical Value = 1.25V).
20	TUVP	Timing delay pin for under voltage protection and over current protection. Its threshold voltage is 1.8V and clamped to 2.9V after full charging. Target of delay time is 38ms and it is realized through external capacitor ($C_{TUVP} = 0.47 \text{uF}$).
21	DTC	Deadtime control input. The deadtime control comparator has an effective 120mV input offset which limits the minimum output dead time. Dead time may be imposed on the output by setting the dead time control input to a fixed voltage, ranging from 0V to 3.3V.
22	C2	Output drive pin for push-pull operation.
23	GND	Ground.
24	C1	Output drive pin for push-pull operation.

Absolute Maximum Ratings

Characteristics	Symbol	Value	Unit	
Supply Voltage	Vcc	40	V	
Collector Output Voltage	VC1,VC2	40	V	
Collector Output Current	IC1,IC2	200	mA	
Power Dissipation (FAN7585)	PD	1.5	W	
Operating Temperature Range	TOPR	-25 to 85	°C	
Storage Temperature Range	TSTG	-65 to 150	°C	

Temperature Characteristics

Characteristics	Symbol	Min.	Тур.	Max.	Unit
Temperature Coefficient of Vref (-25°C \leq Ta \leq 85°C)	$\Delta Vref/\Delta T$	-	0.01	-	%/°C

Electrical Characteristics

(Vcc=20V, Ta=25°C, unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
REFERENCE SECTION			•			
Reference Output Voltage	Vref	Iref=1mA	4.9	5	5.1	V
Line Regulation	$\Delta Vref.LINE$	$15V \leq V_{CC} \leq 30V$	-	2.0	25	mV
Load Regulation	$\Delta Vref.LOAD$	$1mA \le Iref \le 10mA$	-	1.0	15	mV
Temperature Coefficient of Vref ⁽¹⁾	$\Delta Vref/\Delta T$	$-25^\circ C \le Ta \le 85^\circ C$	-	0.01	-	%/°C
Short Circuit Output Current	Isc	Vref = 0	15	35	75	mA
OSCILLATOR SECTION						
Oscillation Frequency	fosc	CT=0.01uF, RT=12k	-	9.4	-	kHz
Frequency Change with Temperature ⁽¹⁾	fosc/T	CT=0.01uF, RT=12k	-	2	-	%
DEAD TIME CONTROL SECTION				•	•	
Input Bias Current	IB(DT)	-	-	-2.0	-10	uA
Maximum Duty Voltage	DCMAX	Pin21 (DTC)=0V	45	48	50	%
Input Throphold Voltage		Zero Duty Cycle	-	3.0	3.3	V
Input Threshold Voltage	VTH(DT)	Max. Duty Cycle	0	-	-	
ERROR AMP SECTION			•		•	
Inverting Reference Voltage	Vref(EA)	-	1.20	1.25	1.30	V
Input Bias Current	IB(EA)	VCOMP=2.5V	-	-0.1	-1.0	uA
Open-Loop Voltage Gain (1)	Gvo	$0.5V \leq VCOMP \leq 3.5V$	70	95	-	dB
Unit-Gain Bandwidth ⁽¹⁾	BW	-	-	650	-	kHz
Output Sink Current	Isink	VCOMP = 0.7V	0.3	0.9	-	mA
Output Source Current	ISOURCE	VCOMP = 3.5V	-2.0	-4.0	-	mA
PWM COMPARATOR SECTION			•			
Input Threshold Voltage	VTH(PWM)	Zero Duty Cycle	-	4	4.5	V
OUTPUT SECTION			•		•	
Output Saturation Voltage	VCE(SAT)	IC = 200mA	-	1.1	1.3	V
Collector Off-State Current	IC(off)	V _{CC} =V _C =30V, V _E =0V	-	2	100	uA
Rising Time ⁽¹⁾	TR	-	-	100	200	ns
Falling Time ⁽¹⁾	TF	-	-	50	200	ns

Electrical Characteristics (Continued)

(V_{cc}=20V, T_a=25°C, unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit		
PROTECTION SECTION								
Over Voltage Protection for +3.3V	Vovp1	-	3.8	4.1	4.3	V		
Over Voltage Protection for +5V	Vovp2	-	6.0	6.4	6.8	V		
Over Voltage Protection for +12V	Vovp3	-	13.5	14.2	15.0	V		
Input Threshold Voltage for PT	Vpt	-	1.20	1.25	1.30	V		
Under Voltage Protection for +3.3V	VUVP1	-	2.1	2.3	2.5	V		
Under Voltage Protection for +5V	VUVP2	-	3.7	4.0	4.3	V		
Under Voltage Protection for +12V	VUVP3	-	9.2	10	10.8	V		
Voltage for Current Reference	VRI		1.21	1.25	1.29	V		
Current Reference ⁽¹⁾	Iref1		10	-	65	uA		
Charging Current for UVP, OCP Delay	ICHG.UVP	C=0.47uF	-16	-21	-28	uA		
UVP, OCP Delay Time	TD.UVP	C=0.47uF, V _{TH} =1.8V	24	38	57	ms		
Offset Voltage of OCP Comparator	VOFFSET		-5	-	5	mV		
REMOTE ON/OFF SECTION								
REM On Input Voltage	VREMH	IREM = -200uA	2.0	-	-	V		
REM Off Input Voltage	VREML	-	-	-	0.8	V		
REM Off Input Bias Current	IREML	V _{REM} = 0.4V	-	-	-1.6	mA		
REM On Open Voltage	VREM(OPEN)	-	2.0	-	5.25	V		
REM On Delay Time	Ton	C=0.1uF	4	8	14	ms		
REM Off Delay Time	Toff	C=0.1uF	16	24	34	ms		
REMOTE ON/OFF SECTION ⁽²⁾				•				
Detecting Input Voltage	VIN(DET)	-	1.20	1.25	1.30	V		
Detecting V5 Voltage	V5(DET)	-	4.1	4.3	4.5	V		
Hysteresis Voltage 1	HY1	COMP1, 2	10	40	80	mV		
Hysteresis Voltage 2	HY2	COMP3	0.6	1.2	-	V		
PG Output Load Resistor	R _{PG}	-	0.5	1	2	kΩ		
Charging Current for PG Delay	ICHG.PG	C=2.2uF	-10	-15	-23	uA		
PG Delay Time	TD.PG	C=2.2uF, VTH=1.8V	100	260	500	ms		
PG Output Saturation Voltage	VSAT(PG)	IPG=10mA	-	0.2	0.4	V		
TOTAL DEVICE								
Standby Supply Current	ICC	-	-	10	20	mA		

Note:

1. These parameters, although guaranteed over their recommended operating conditions are not 100% tested in production.

2. REM on delay time (Pin6 REM: "L" \rightarrow "H"), REM off delay time (Pin6 REM: "H" \rightarrow "L")

Application Informations









1. OVP Block



The OVP function is simply realized by connecting Pin14, Pin16, Pin18 to each secondary outputs. R1, R2, R3, R4, R5, R6 are internal resistors of the IC. Each OVP level is determined by resistor ratio and the typical values are 4.1V/6.4V/14.2V respectively.

• OVP detecting voltage for +3.3V

$$V_{\text{OVP1}}(+3.3V) = \frac{R_1 + R_2}{R_2} \times V_A = \frac{R_1 + R_2}{R_2} \times \text{Vref} = 4.1V$$

• OVP detecting voltage for +5V

$$V_{OVP2}(+5V) = \frac{R_3 + R_4}{R_4} \times V_B = \frac{R_3 + R_4}{R_4} \times Vref = 6.4V$$

• OVP detecting voltage for +12V

$$V_{OVP3}(+12V) = \frac{R_5 + R_6}{R_6} \times V_C = \frac{R_5 + R_6}{R_6} \times Vref = 14.2V$$

Especially, Pin19(PT) is prepared for extra OVP input or another protection signal. That is, if you want over voltage protection of extra output voltage, then you can make a function with two external resistors.

• OVP detecting voltage for PT

$$PT = \frac{R_{101} + R_{102}}{R_{102}} \times V_D = \frac{R_{101} + R_{102}}{R_{102}} \times Vref$$

In the case of OVP, a system designer should know a fact that the main power can be dropped after a little time because of system delay, even if PWM is triggered by OVP. So when the OVP level is tested with a set, you should check the secondary outputs(+3.3V/+5V/+12V) and PG(Pin11) simultaneously. Then you can know the each OVP level as checking each output voltage in just time that PG(Pin11) is triggered from high to low.

2. UVP Block



The block is made up of a comparator with three detecting inputs and without hysteresis voltage. Each UVP level is determined by resistor ratio and the typical values are 2.3V/4.0V/10V respectively.

• UVP detecting voltage for +3.3V

$$V_{UVP1}(+3.3V) = \frac{R_1 + R_2}{R_2} \times V_A = \frac{R_1 + R_2}{R_2} \times Vref = 2.3V$$

• UVP detecting voltage for +5V

$$V_{UVP2}(+5V) = \frac{R_3 + R_4}{R_4} \times V_B = \frac{R_3 + R_4}{R_4} \times Vref = 4V$$

• UVP detecting voltage for +12V

$$V_{UVP3}(+12V) = \frac{R_5 + R_6}{R_6} \times V_C = \frac{R_5 + R_6}{R_6} \times Vref = 10V$$

In the case of UVP, a system designer should know a fact that the main power can be dropped after some delay. (38 msec@CTUVP=0.47 uF)

So when the UVP level is tested with a set, you should remove protection delay capacitor(Pin20) and check PG(Pin11). You can know the each UVP level as checking each output voltage in just time that PG(Pin11) is triggered from high to low.

3. OCP Block



It also has OCP function for +3.3V,+5V,+12V outputs. The block is made up of three comparators. Pin17(IS12), pin15(IS5) and pin13(IS33) are current sense inputs for +12V, +5V and +3.3V outputs respectively. These pins are connected to the current sensing resistor or inductor.

Each OCP level is determined by RI resistor, so you can define over current protection level by changing RI resistor. Pin8(RI) voltage is always 1.25V, so if you connect $62k\Omega$ resistor, the reference current is 20uA(Iref1).

If the voltage drop of the sense resistor or inductor is larger than offset voltage ($V_{offset} = R_{offset} \times 5 \times Iref1$), the DTC becomes "High" after some delay(38ms at CTUVP=0.47uF) and the main SMPS is turned off. That means the output voltage(+3.3V, +5V, +12V) will be ground level.

After main power is turned off at OCP and initialized by REM, if REM signal is changed from "High" to "Low", main power becomes operational.

For example, if you want to define 5V output OCP level at 10A in the condition of equivalent resistor(Rs)= 5m Ω , you can determine the offset voltage resistor(Roffset) as following method.

- Iref1 = $1.25V / 62k\Omega = 20uA$
- $V_{offset} = R_S \times 5 \times Iref1 = 5m\Omega \times 10A = 50mV$
- Therefore, $R_{offset} = 50 mV / (5 \times Iref1) = 500 \Omega$

By the way, OCP output signal can be delayed by protection delay capacitor(CTUVP) and its delay time is decided by the value of CTUVP.

$$Tuvp \approx \frac{C_{TUVP}^{*}\Delta V}{\Delta I} = \frac{0.47uF^{*}1.7V}{21uA} = 38msec$$

If you use too small (or large) capacitor, the charging time would decrease (or increase) very much and it can cause malfunction at the transient time. So you have to choose the reasonable delay time for system optimization by changing the external capacitor value.

4. Remote On/Off & Delay Block



Remote On/Off section is controlled by a microprocessor. If a high signal is supplied to the Remote On/Off input(Pin6), the output of COMP6 becomes high status. The output signal is transferred to ON/OFF delay block and PG block. If no signal is supplied to Pin6, Pin6 maintains high status(=5V) for pull-up resistor, Rpull.

When Remote On/Off is high, it produces PWM(Pin6) "High" signal after ON delay time (about 8ms with C_{TREM}=0.1uF) for stabilizing system. Then, all outputs (+3.3V, +5V, +12V) are grounded.

When Remote On/Off is changed to "Low", it produces PWM "Low" signal after Off delay time (about 24ms with CTREM=0.1uF) for stabilizing the system. If REM is low, then PWM is low. That means the main SMPS is operational. When REM is high, PWM is high and the main SMPS is turned off.

Remote On/Off delay time can be calculated by following equation.

$$Ton = K_1 \times \frac{C_{TREM} \times \Delta Von}{Ion} \approx 0.95 \times \frac{0.1uF \times 2V}{23uA} = 8msec$$
$$Toff = K_2 \times \frac{C_{TREM} \times \Delta Voff}{Ioff} \approx 0.8 \times \frac{0.1uF \times 2.1V}{7uA} = 24msec$$

k1, k2: constant value gotten by test

In above equation, a typical capacitor value is 0.1uF. If the capacitor is changed to larger value, it can cause malfunction in case of AC power on at "REM=High". Because PWM maintains Low status and main power turns on for on delay time. So you should use 0.1uF or smaller capacitor.

5. Power Good Signal Generator



Power Good Signal Generator circuit generates "ON or OFF" signal depending on the status of output voltage to prevent the malfunctions of following systems like microprocessor, etc. caused by the output instability at power on or off. At power on, it produces PG "High" signal after some delay time(about 260ms with CTPG=2.2uF) for stabilizing output voltage. At power off, it produces PG "Low" signal without delay time by sensing the status of power source for protecting following systems. Vcc detection point(Pin9) can be calculated by following equation. Recommended values of R11, R12 are determined by the following equation.

$$DET = 1.25V \times \left(1 + \frac{R11}{R12}\right) = 17.2V$$

The COMP3 creates PG "Low" without delay when +5V output falls to less than 4.0V to prevent some malfunction at transient status, thus it improves system stability.

When Remote On/Off signal is high, it generates PG "Low" signal without delay. It means that PG becomes "Low" before main power is grounded.

PG delay time(TPG) is determined by capacitor value(CTPG), threshold voltage of COMP3 and the charging current and its euqation is as following.

$$T_{PG} = \frac{C_{TPG} \times \Delta V}{Ichg} \approx \frac{C_{TPG} \times Vth}{Ichg} = \frac{2.2uF \times 1.8V}{15uA} \approx 260 \text{msec}$$

Considering the lightning surge and noise, there are two types of protections. One is a few time delay between TPG and PG for safe operation and another is some noise margin of Pin10.

Noise_Margin_of_TpG = $V_{Pin10}(max)$ - Vth(L) = 2.9V - 0.6V = 2.3V

Typical Application Circuit



Mechanical Dimensions

Package

Dimensions in millimeters

(E)

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7.62T/P (7.52 ± 0.25)

e

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0.254-0.10

9.5 ± 0.5 (END TO END)

(8–R0.3)



24-SDIP

NOTE 1. These dimensions of not include mold protrusion 2. () is reference 3. () is assy out duality 4. PKG Surface : Matt 5. Notch area 3 FAN7585

Ordering Information

Product Number	Package	Operating Temperature
FAN7585	24-SDIP	-25°C ~ 85°C

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